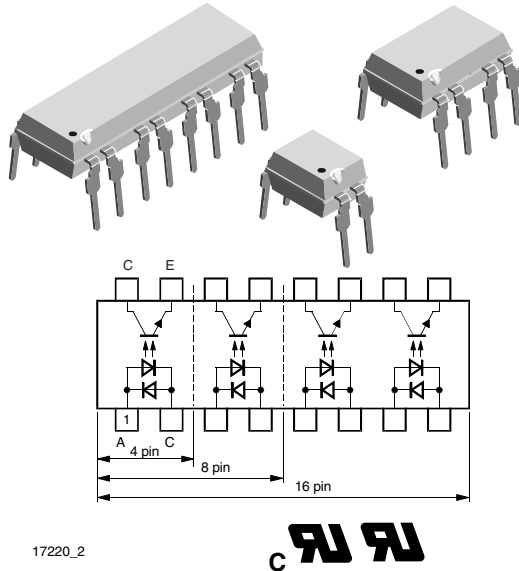


Optocoupler, Phototransistor Output, AC Input



17220_2



DESCRIPTION

The K814P, K824P, K844P consist of a phototransistor optically coupled to 2 gallium arsenide infrared emitting diodes (reverse polarity) in 4 pin (single); 8 pin (dual) or 16-pin (quad) plastic dual inline package. The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

FEATURES

- Endstackable to 2.54 mm (0.1") spacing
- DC isolation test voltage $V_{ISO} = 5000 V_{RMS}$
- Low coupling capacitance of typical 0.3 pF
- Current transfer ratio (CTR) of typical 100 %
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

APPLICATIONS

- Feature phones
- Answering machines
- PBX
- Fax machines

AGENCY APPROVALS

- UL1577, file no. E76222 system code U, double protection
- C-UL CSA 22.2, bulletin 5A

ORDER INFORMATION

PART	REMARKS
K814P	CTR > 20 %, single channel, DIP-4
K824P	CTR > 20 %, dual channel, DIP-8
K844P	CTR > 20 %, quad channel, DIP-16

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Forward current		I_F	± 60	mA
Forward surge current	$t_p \leq 10 \mu s$	I_{FSM}	± 1.5	A
Power dissipation		P_{diss}	100	mW
Junction temperature		T_j	125	°C
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 ms$	I_{CM}	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	°C

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
AC isolation test voltage (RMS)	$t = 1.0 \text{ min}$	V_{ISO}	5000	V_{RMS}
Total power dissipation		P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	- 40 to +100	°C
Storage temperature range		T_{stg}	- 55 to + 125	°C
Soldering temperature ⁽²⁾	2 mm from case, $t \leq 10 \text{ s}$	T_{sld}	260	°C

Notes

⁽¹⁾ $T_{\text{amb}} = 25 \text{ °C}$, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 50 \text{ mA}$	V_F		1.25	1.6	V
Reverse current	$V_R = \pm 6 \text{ V}$	I_R			10	μA
OUTPUT						
Collector emitter voltage	$I_C = 100 \text{ }\mu\text{A}$	V_{CEO}	70			V
Emitter collector voltage	$I_E = 100 \text{ }\mu\text{A}$	V_{ECO}	7			V
Collector dark current	$V_{\text{CE}} = 20 \text{ V}$, $I_F = 0$, $E = 0$	I_{CEO}			100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = \pm 10 \text{ mA}$, $I_C = 1 \text{ mA}$	V_{CEsat}			0.3	V
Cut-off frequency	$I_F = \pm 10 \text{ mA}$, $V_{\text{CE}} = 5 \text{ V}$, $R_L = 100 \text{ }\Omega$	f_c		100		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	C_k		0.3		pF

Note

$T_{\text{amb}} = 25 \text{ °C}$, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$V_{\text{CE}} = 5 \text{ V}$, $I_F = \pm 5 \text{ mA}$	K814P	CTR	20		300	%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_d		3		μs
Rise time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_r		3		μs
Fall time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_f		4.7		μs
Storage time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_s		0.3		μs
Turn-on time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_{on}		6		μs
Turn-off time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \text{ }\Omega$ (see figure 1)	t_{off}		5		μs
Turn-on time	$V_S = 5 \text{ V}$, $I_C = 10 \text{ mA}$, $R_L = 1 \text{ k}\Omega$ (see figure 1)	t_{on}		9		μs
Turn-off time	$V_S = 5 \text{ V}$, $I_C = 10 \text{ mA}$, $R_L = 1 \text{ k}\Omega$ (see figure 1)	t_{off}		18		μs

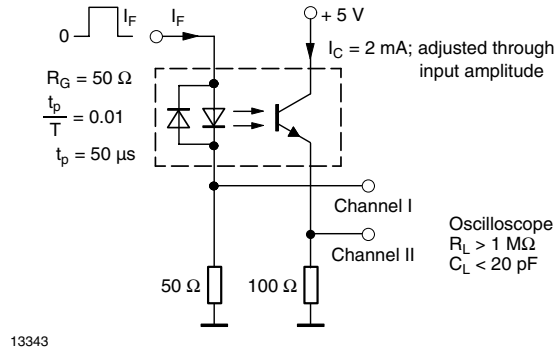


Fig. 1 - Test Circuit, Non-Saturated Operation

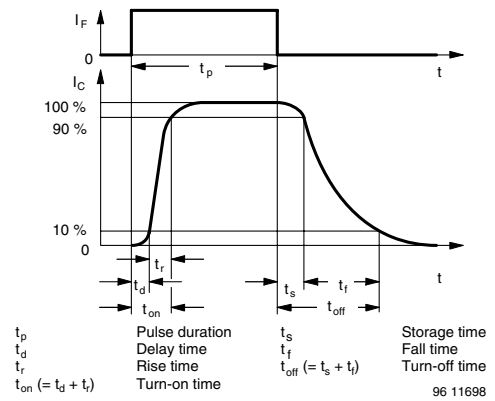


Fig. 3 - Switching Times

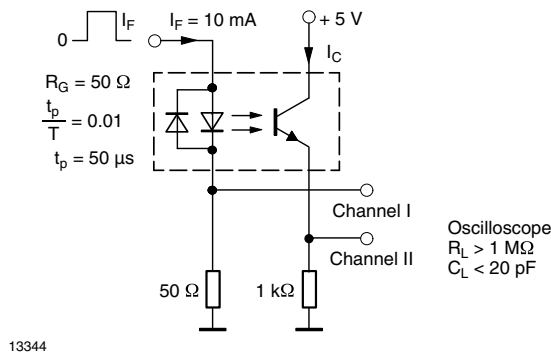


Fig. 2 - Test Circuit, Saturated Operation

TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

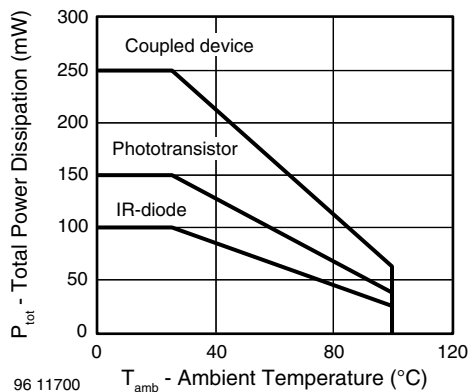


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

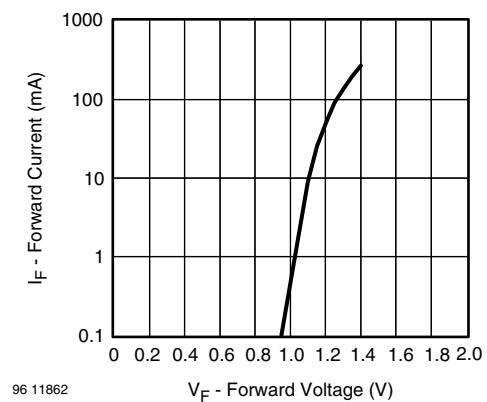


Fig. 5 - Forward Current vs. Forward Voltage

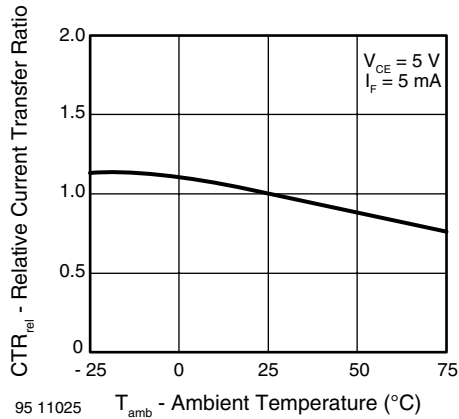


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

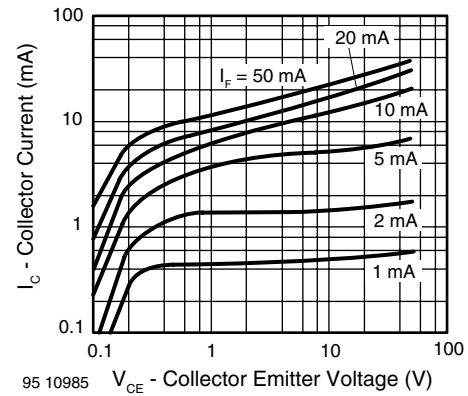


Fig. 9 - Collector Current vs. Collector Emitter Voltage

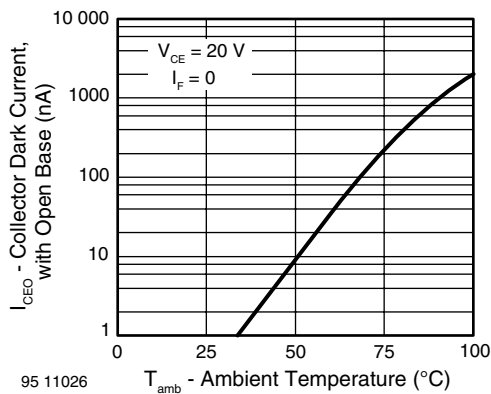


Fig. 7 - Collector Dark Current vs. Ambient Temperature

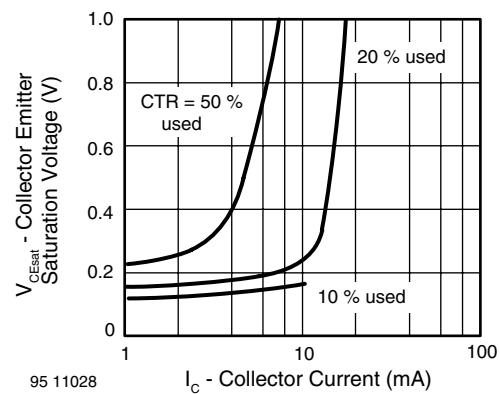


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

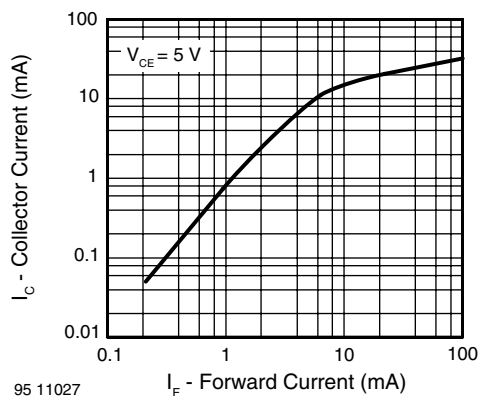


Fig. 8 - Collector Current vs. Forward Current

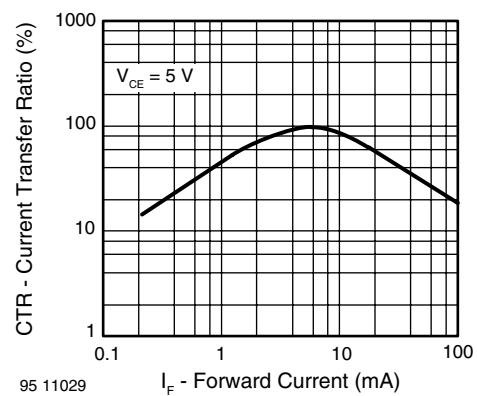


Fig. 11 - Current Transfer Ratio vs. Forward Current

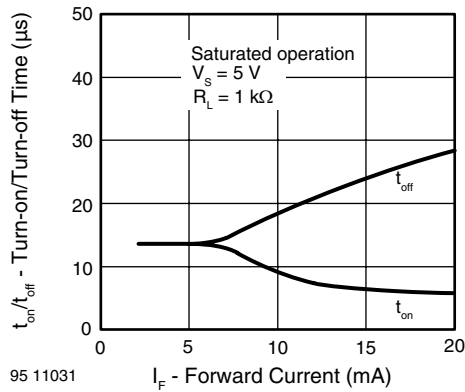


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

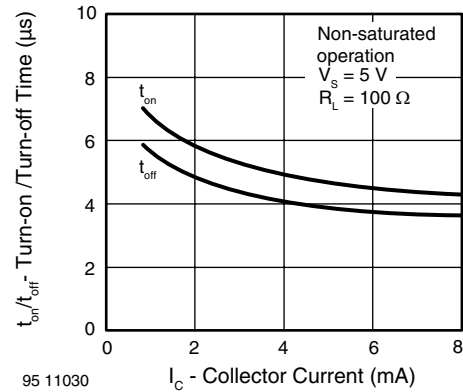
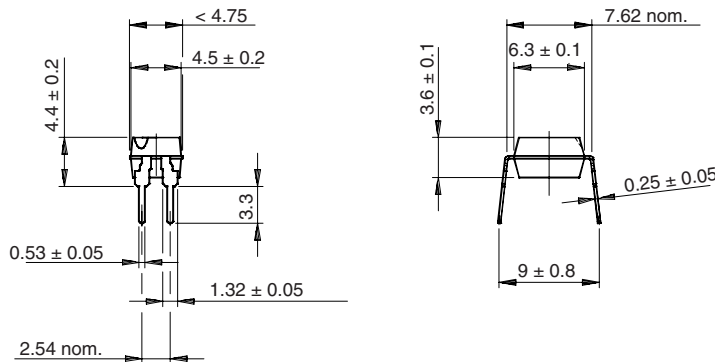


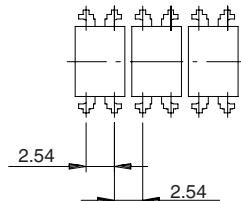
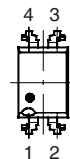
Fig. 13 - Turn-on/Turn-off Time vs. Collector Current

PACKAGE DIMENSIONS in millimeters

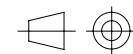


E. g.:
Special features: endstackable
to 2.54 mm (0.100") spacing

Weight: ca. 0.25 g
Creepage distance: $> 6 \text{ mm}$
Air path: $> 6 \text{ mm}$
after mounting on PC board



Drawing-No.: 6.544-5302.03-4
Issue: 5; 20.03.02



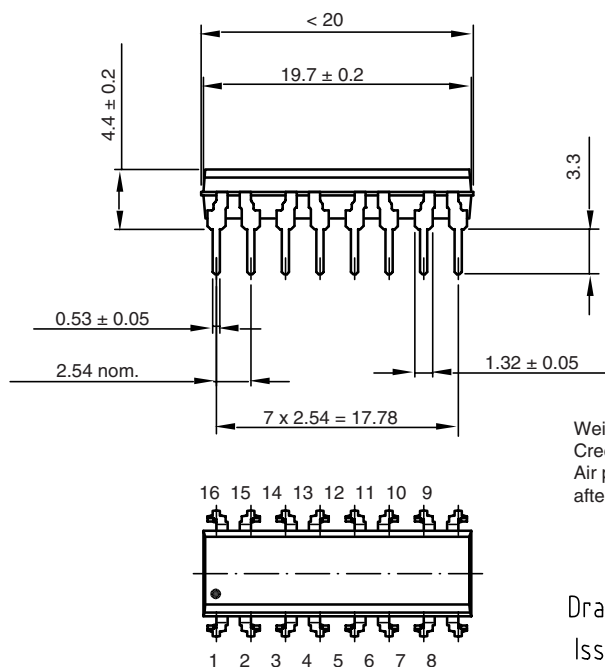
technical drawings
according to DIN
specifications

14789

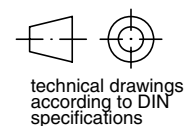
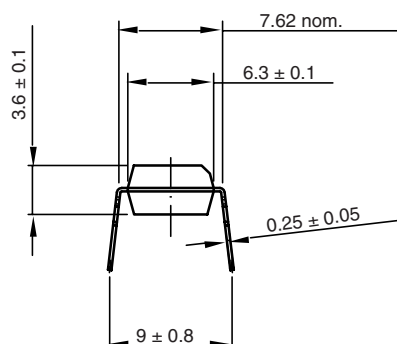
K814P, K824P, K844P

Vishay Semiconductors

Optocoupler, Phototransistor
Output, AC Input



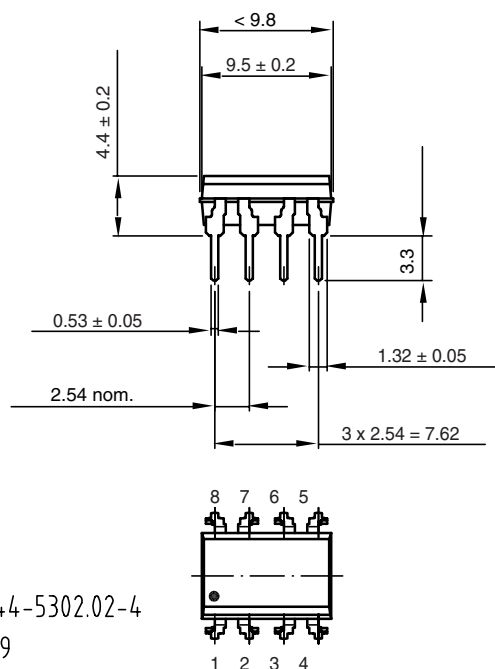
Weight: ca. 1.08 g
Creepage distance: > 6 mm
Air path: > 6 mm
after mounting on PC board



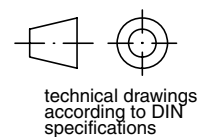
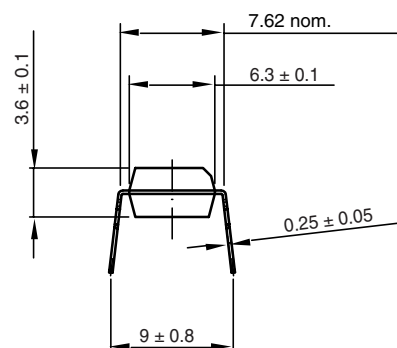
Drawing-No.: 6.544-5302.01-4

Issue: 4; 02.06.99

14783



Weight: ca. 0.55 g
Creepage distance: > 6 mm
Air path: > 6 mm
after mounting on PC board



Drawing-No.: 6.544-5302.02-4

Issue: 4; 02.06.99

14784

**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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